

## Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

[Diodes Incorporated](#)  
[MMBTH24-7](#)

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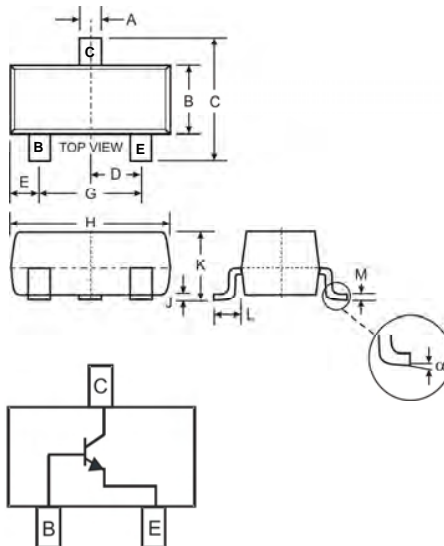
[sales@integrated-circuit.com](mailto:sales@integrated-circuit.com)

**Features**

- Designed for VHF/UHF Amplifier Applications and High Output VHF Oscillators
- High Current Gain Bandwidth Product
- Ideal for Mixer and RF Amplifier Applications with collector currents in the 100 $\mu$ A - 30 mA Range
- **Lead, Halogen and Antimony Free, RoHS Compliant "Green" Device (Notes 3 and 4)**

**Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.008 grams (approximate)



SOT-23		
Dim	Min	Max
A	0.37	0.51
B	1.20	1.40
C	2.30	2.50
D	0.89	1.03
E	0.45	0.60
G	1.78	2.05
H	2.80	3.00
J	0.013	0.10
K	0.903	1.10
L	0.45	0.61
M	0.085	0.180
$\alpha$	0°	8°
All Dimensions in mm		

**Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CB0</sub>	40	V
Collector-Emitter Voltage	V <sub>CE0</sub>	40	V
Emitter-Base Voltage	V <sub>EBO</sub>	4.0	V
Collector Current - Continuous (Note 1)	I <sub>C</sub>	50	mA
Power Dissipation (Note 1)	P <sub>d</sub>	300	mW
Thermal Resistance, Junction to Ambient (Note 1)	R <sub>θJA</sub>	417	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

**Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 2)</b>					
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	40	—	V	I <sub>C</sub> = 1mA, I <sub>B</sub> = 0
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	40	—	V	I <sub>C</sub> = 100 $\mu$ A, I <sub>E</sub> = 0
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	4.0	—	V	I <sub>E</sub> = 10 $\mu$ A, I <sub>C</sub> = 0
Collector Cutoff Current	I <sub>CB0</sub>	—	100	nA	V <sub>CB</sub> = 30V, I <sub>E</sub> = 0
Emitter Cutoff Current	I <sub>EBO</sub>	—	100	nA	V <sub>EB</sub> = 2V, I <sub>C</sub> = 0
<b>ON CHARACTERISTICS (Note 2)</b>					
DC Current Gain	h <sub>FE</sub>	30	—	—	I <sub>C</sub> = 8mA, V <sub>CE</sub> = 10.0V
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	—	0.5	V	I <sub>C</sub> = 4mA, I <sub>B</sub> = 400 $\mu$ A
Base-Emitter On Voltage	V <sub>BE(SAT)</sub>	—	0.95	V	I <sub>C</sub> = 4mA, V <sub>CE</sub> = 10.0V
<b>SMALL SIGNAL CHARACTERISTICS</b>					
Current Gain-Bandwidth Product	f <sub>T</sub>	400	—	MHz	V <sub>CE</sub> = 10V, f = 100MHz, I <sub>C</sub> = 8mA
Collector-Base Capacitance	C <sub>CB</sub>	—	0.7	pF	V <sub>CB</sub> = 10V, f = 1.0MHz, I <sub>E</sub> = 0
Collector-Base Feedback Capacitance	C <sub>RB</sub>	—	0.65	pF	V <sub>CB</sub> = 10V, f = 1.0MHz, I <sub>E</sub> = 0
Collector-Base Time Constant	R <sub>b</sub> 'C <sub>c</sub>	—	9	ps	I <sub>C</sub> = 4mA, V <sub>CB</sub> = 10V, f = 31.8MHz

- Notes:
1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch pad layout, as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
  2. Short duration pulse test used to minimize self-heating effect.
  3. No purposefully added lead. Halogen and Antimony Free.
  4. Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V9 are built with Non-Green Molding Compound and may contain Halogens or Sb<sub>2</sub>O<sub>3</sub> Fire Retardants.

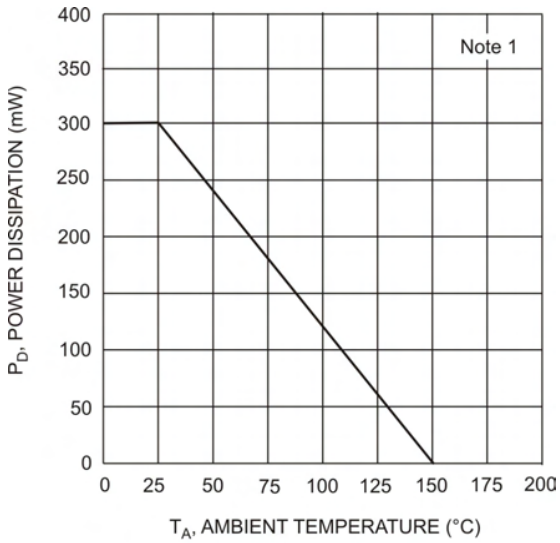


Fig. 1, Max Power Dissipation vs Ambient Temperature

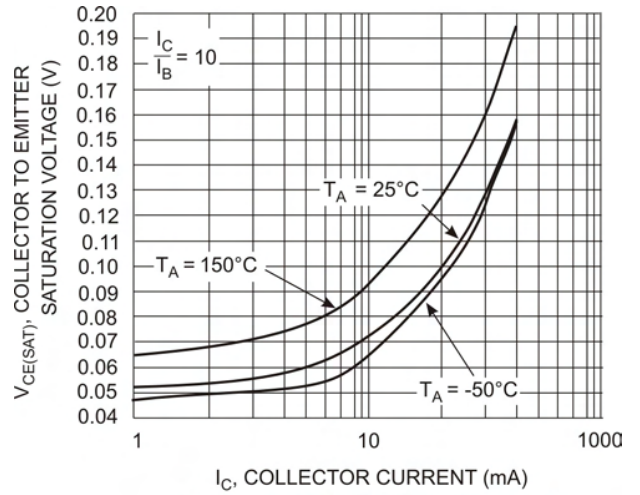


Fig. 2 Collector Emitter Saturation Voltage vs. Collector Current

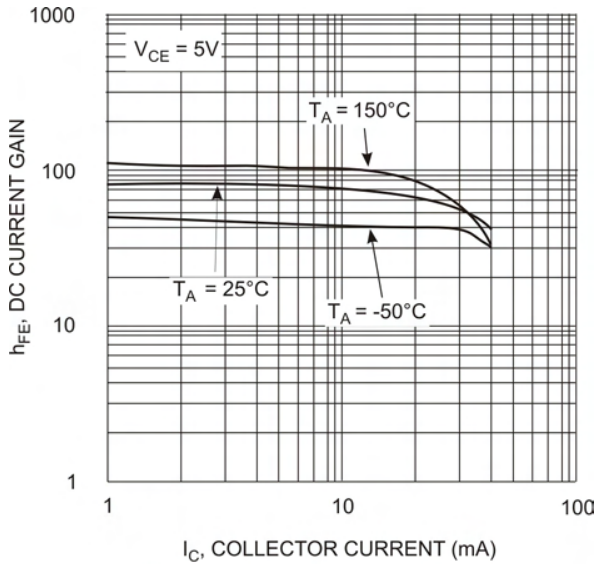


Fig. 3, DC Current Gain vs. Collector Current

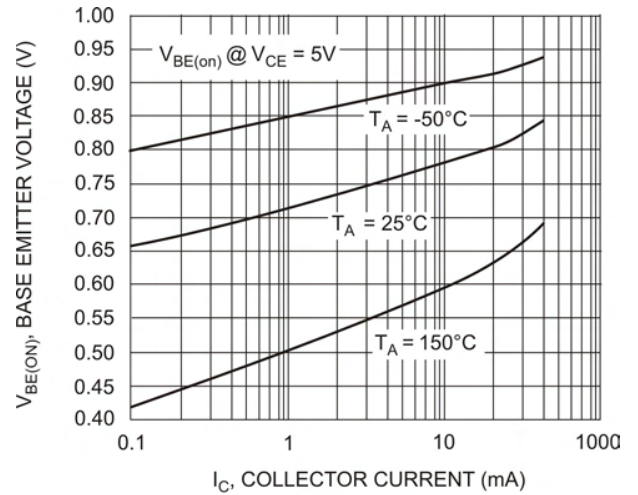


Fig. 4 Base Emitter Voltage vs. Collector Current

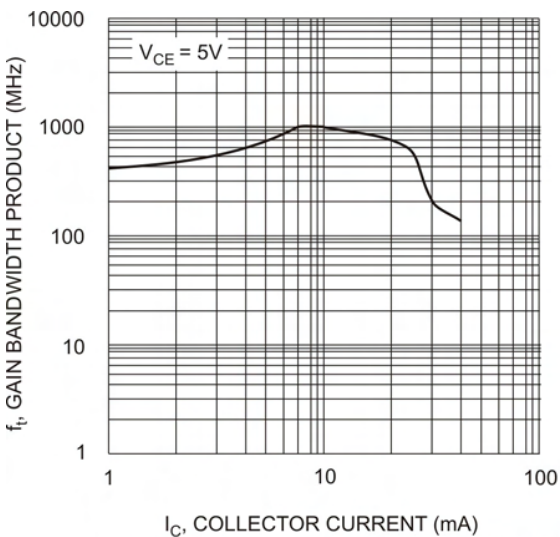


Fig. 5, Gain Bandwidth Product vs Collector Current

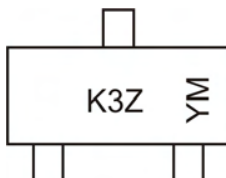


**Ordering Information** (Note 5)

Device	Packaging	Shipping
MMBTH24-7-F	SOT-23	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

**Marking Information**



K3Z = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year ex: N = 2002  
 M = Month ex: 9 = September

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	L	M	N	P	R	S	T	U	V	W	X	Y	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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